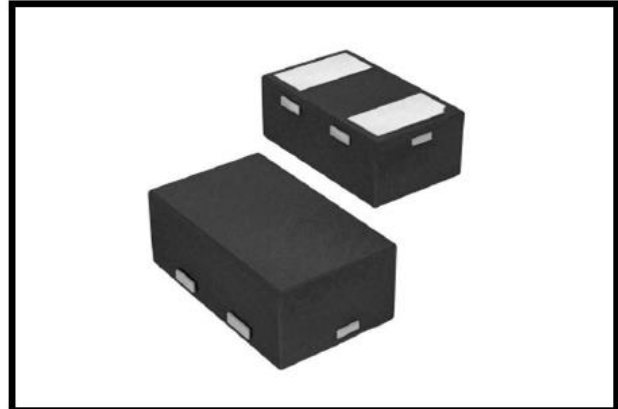


## PT0672NH – ESD Protection Diode

### Feature

- 2200 Watts peak pulse power (8/20 $\mu$ s)
- Unidirectional Configuration
- Solid state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one data/power line
- IEC61000-4-2 (ESD)  $\pm$ 30kV (Air),  $\pm$ 30kV (Contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning): 160A (8/20 $\mu$ s)



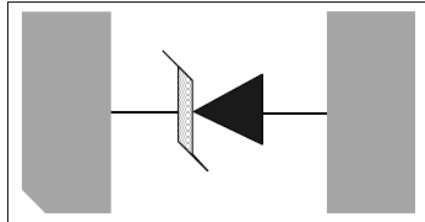
### Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

### Mechanical Data

- DFN1610 package
- Molding compound flammability rating: UL94 V-0
- Tape and Reel Packaging
- RoHS/WEEE Compliant

### Schematic and PIN Configuration



DFN1610

### Maximum Rating

Parameter	Symbol	Limit	Unit
IEC61000-4-2 ESD Voltage – Air Mode	$V_{ESD}^{(1)}$	$\pm$ 30	kV
IEC61000-4-2 ESD Voltage – Contact Mode		$\pm$ 30	
Peak Pulse Power	$P_{PP}^{(2)}$	2200	W
Peak Pulse Current	$I_{PP}^{(2)}$	160	A
Maximum Lead Solder Temperature (10 seconds duration)	$T_L$	260	$^{\circ}$ C
Junction Temperature	$T_J$	-55~125	$^{\circ}$ C
Storage Temperature Range	$T_{stg}$	-55~125	$^{\circ}$ C

Note:

1. Device stressed with ten non-repetitive ESD pulses.
2. Non-repetitive current pulse 8/20 $\mu$ s exponential decay waveform according to IEC61000-4-5.
3. All ratings are measured at environmental temperature of TA = 25  $^{\circ}$ C unless otherwise noted.

## PT0672NH – ESD Protection Diode

### Electrical Characteristics

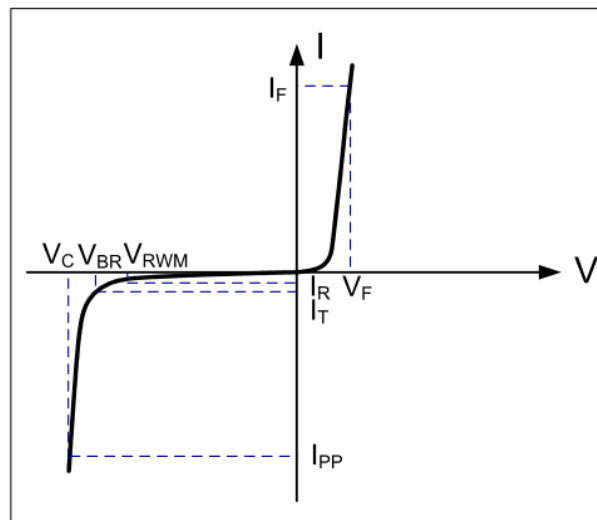
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse Stand-off Voltage	$V_{RWM}^{(1)}$				6.8	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	7.0			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 6.8\text{V}$			1.0	$\mu\text{A}$
Clamping Voltage	$V_C^{(2)}$	$I_{PP} = 160\text{A}$		14		V
Junction Capacitance	$C_J$	$V_R = 0\text{V}, f = 1\text{MHz}$		1100		pF

Note:

1. Other voltages available upon request.
2. Non-repetitive current pulse 8/20 $\mu\text{s}$  exponential decay waveform according to IEC61000-4-5.
3. All ratings are measured at environmental temperature of  $T_A = 25^\circ\text{C}$  unless otherwise noted.

### Electrical Parameters

Symbol	Parameter
$V_C$	Clamping Voltage @ $I_{PP}$
$I_{PP}$	Peak Pulse Current
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{RWM}$	Reverse Stand-off Voltage
$V_F$	Forward Voltage @ $I_F$



## PT0672NH – ESD Protection Diode

### Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

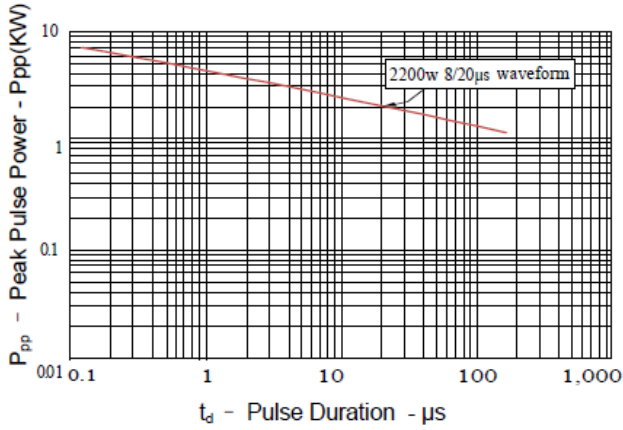


Figure 2: Power Derating Curve

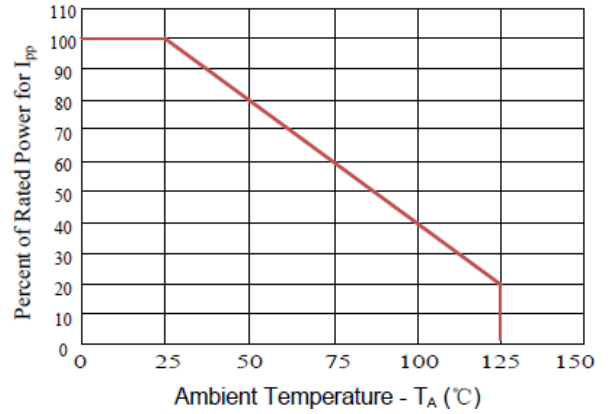


Figure 3: Pulse Waveform

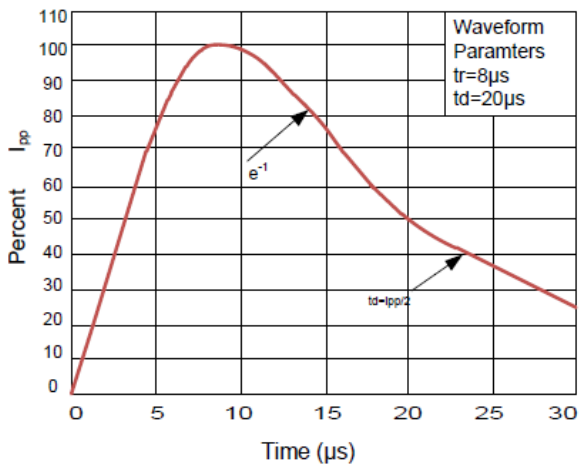
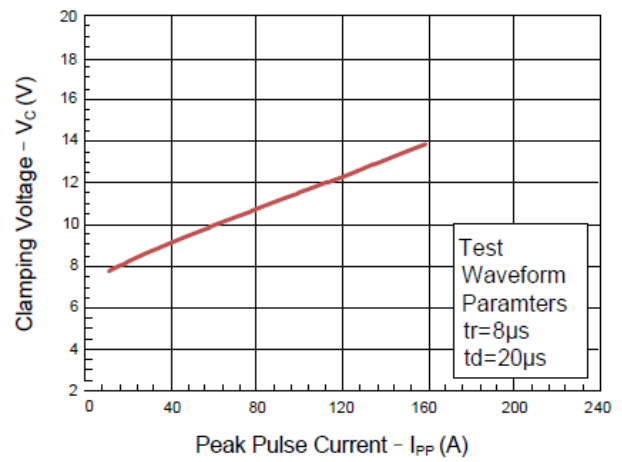
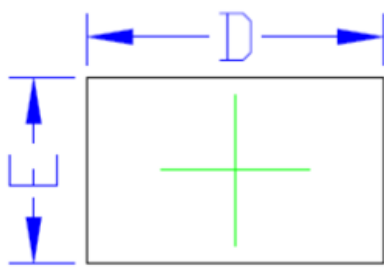


Figure 4: Clamping Voltage vs. I<sub>pp</sub>

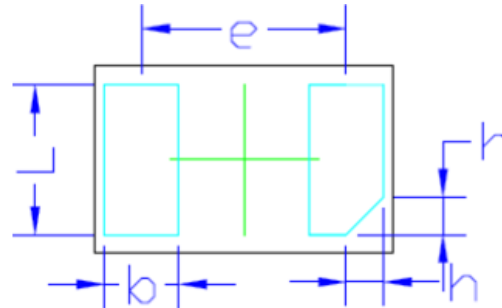


## PT0672NH – ESD Protection Diode

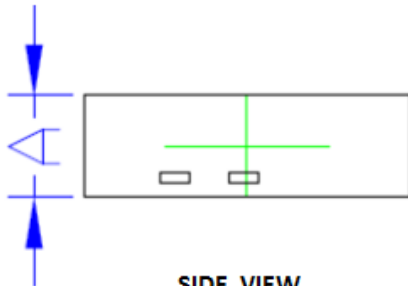
### DFN1610 Package Outline Dimensions



TOP VIEW



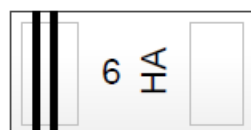
BOTTOM VIEW



SIDE VIEW

Symbol	Dimensions (mm)		
	Min	Typ	Max
A	0.45	0.50	0.55
D	1.55	1.60	1.65
E	0.95	1.00	1.05
b	0.35	0.40	0.45
L	0.75	0.80	0.85
e	1.10 BSC		
h	0.15	0.20	0.25

### Marking



### Packaging Information

Order Code	Packaging	Reel Size	PCS/Reel
PT0672NH	DFN1610	7 inch	10,000